

PRELIMINARY

MMF Pigtailed Coaxial Single Photon Avalanche Diode (SPAD) PGA-314-MM

1. Product Description

The RMY Electronics SPAD is an InGaAs/InP avalanche photodetector (transferred technology from previous Princeton Lightwave Inc.) designed specifically for single photon counting applications. The device is intended for use at voltage biases above the breakdown voltage (in the so-called "Geiger mode") so that a single photon incident on the detector will give rise to a macroscopic current pulse. Combined with appropriate pulse detection circuitry, this device allows for the detection of single photons in the wavelength range from 0.95 to 1.65 µm.

The RMY SPAD described in this datasheet is a back-illuminated device with 16µm diameter chip, provided in a GI 62.5/125µm multi-mode fiber pigtailed TO-46 can.

2. Performance Specifications

Linear Mode Parameters (1550nm, all voltages and currents are reverse biased)

Parameter Description	Took Conditions	Specifications			l loi4
	Test Conditions		Тур	Max	Unit
Breakdown voltage, V _b	case temperature 295 K, I _d = 10 uA	50	70	90	V
Temperature dependence of V_b , γ	ΔV _b /ΔT, linear approximation		0.1		V/ºC
Total Dark Current, Id	case temperature 295 K, M=10; primarily non-multiplied l₃		0.3		nA
Capacitance, (C)	M=10, 1MHz		0.25		pF

Geiger Mode Parameters (1550nm, Case Temperature=233K, No blanking)

Test Conditions	Parameter	Parameter	PGA-314-MM		Unit
rest Conditions	Description	Definition	Min	Max	
2MHz Repetition Rate Gating, 1550nm 1MHz 0.1Photon/Pulse	Detection Efficiency(DE)	at DCR maximum	20		%
	Dark Count Rate(DCR)	at DE minimum		10	kHz

3. Maximum Ratings

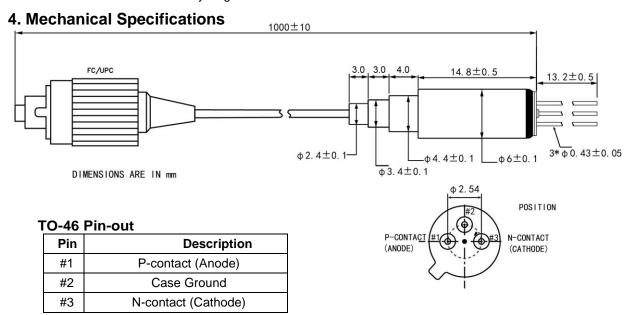
Parameter	Conditions	Min.	Max.	Units
Forward Current	Continuous bias		+1	mA
Forward Voltage	Continuous bias		+1	V
Reverse Current	Continuous bias		-1	mA
Reverse Voltage	Continuous bias		-(V _b +5)	V
Reverse Voltage	Pulsed (gated operation)		-(V _b +10)	V
Optical Power	Continuous wave (CW)		1	mW
Case Temperature		-60	65	°C

Maximum ratings indicate conditions that the device can be exposed for short periods of time without damage. Although InGaAs SPADs are sometimes operated at temperatures below -60 °C, these devices have not yet been tested to establish their reliability characteristics at very low temperatures and under

Version 3.0 July 2021 1/2



extreme conditions of thermal cycling.



5. Product Handling

These avalanche photodiodes are sensitive to electrostatic discharge (ESD) and should be handled with appropriate caution, including the use of ESD protective equipment such as grounding straps and anti-static mats.

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Version 3.0 July 2021 2 / 2